NSN 5961-01-100-1915

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-100-1915 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 emitter to base voltage, static, collector open and 40.0 collector to emitter voltage/static/base open and 40.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 200.00 milliamperes zero-gate-voltage source current blank and 50.00 milliamperes zero-gate-voltage source current of standard range **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: